



Load Switching Applications

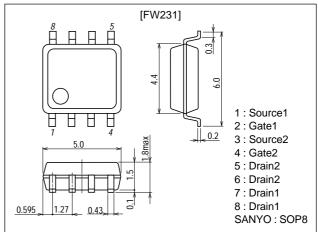
Features

- · Low ON resistance.
- · 2.5V drive.

Package Dimensions

unit:mm

2129



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	I _D		9	Α
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	52	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (1000mm ² ×0.8mm) 1unit	1.7	W
Total Dissipation	PT	Mounted on a ceramic board (1000mm ² ×0.8mm)	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =9A	16	24		S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =9A, V _{GS} =4V		15	20	mΩ
	R _{DS(on)} 2	I _D =2A, V _{GS} =2.5V		20	27	mΩ

Marking: W231 Continued on next page.

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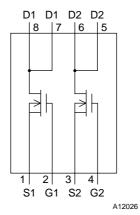
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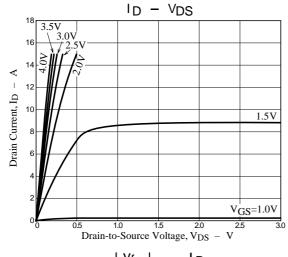
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1950		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		550		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		370		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		24		ns
Rise Time	t _r	See specified Test Circuit		440		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		200		ns
Fall Time	t _f	See specified Test Circuit		300		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =9A		60		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =9A		2.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =9A		10		nC
Diode Forward Voltage	V _{SD}	I _S =9A, V _{GS} =0		0.82	1.2	V

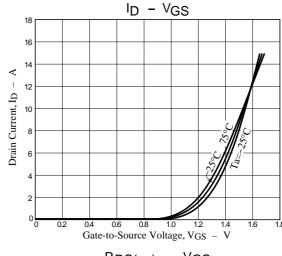
Switching Time Test Circuit

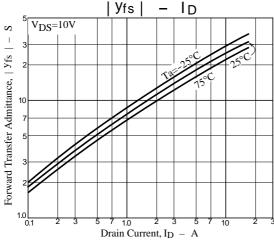
V_{IN} 4V Π 6V Π V_{ID}=10V I_D=9A R_L=1.1Ω PW=10μs D.C.≤1% P.G Π FW231

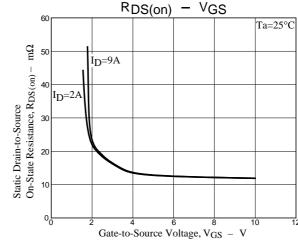
Electrical Connection

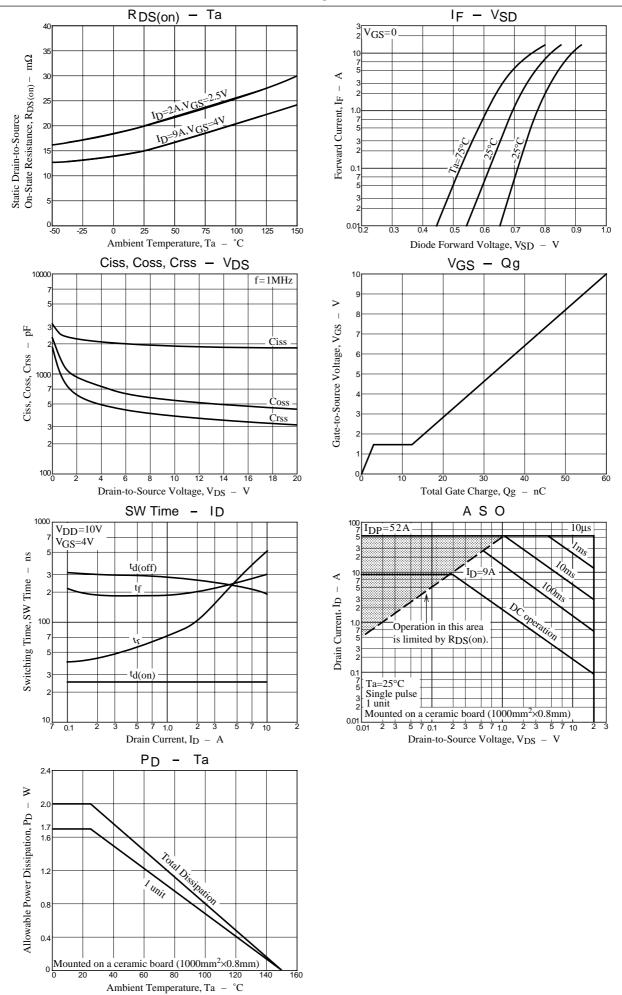












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